## SANYO SEMICONDUCTOR CORP

## 12E D 7997076 0003696 4

1111

•••••

. 11

Discontinued Transistors

T=27-01

\$>	Remark					5																					·	
	+ c, b,	ĸ	\$3	15	15	52	150	I	I	I	I	I	150	I	ı	1	ŀ	1	1	1	I	3.5	ى.	ŝ	1	ы. С	1	3.0
	N C	10	10	10	9	91	91	I	ł	1	1	I	10	1	I	I	1	1	l	ŀ	I	9	10	10	1	9	I	9
	±۲ +۲	180	180	100	100	180	15	15	15	15	15	15	31	ଷ	8	8	8	ଛ	ଷ	œ	15	120	470	470	200	470	200	150
	гĭ	Sem	20m	20 10 10	ŝ	n n n n n n n n n n n n n n n n n n n	-	1	-	-				ŝ	7	4		т	1	100m	1m	10m	<b>5</b>	and and a	20m	20m	8 10 10	l n
a=25~(	Vcb Vce	10	9	9	10	10	ŝ	S	ŝ	ഹ	പ	S	S	ŋ	Q	S	ы	5	5	5	9	10	8	91	9	91	91	9
Electrical Characteristics/1a=25°C	h <sub>rE</sub> th <sub>fe</sub>	60~320	60~320	60~320	60~320	60-320	40~320	40~320	40 - 320	40~320	40~320	40~320	$60 \sim 200$	5000	2000	4000	$70 \sim 280$	70~280	70 - 280	$40\sim 200$	93 +	$10 \sim 200$	25~560	$40 \sim 560$	80	$25 \sim 560$	8	40~850
Charac		1	t	I	l	I	1	I	I	I	1	1	I	I	ı	I.	I	I	1	I	1k	l	t	1	ı	I	1	1
ctrical	ŗ	50m	50m	50m	20m	50m		1	-	ц	г	1	-	ഹ	2	4	-		ī	0.3	1 m	5 m	20m	20m	20m	20m	20m	la I
뷕	V <sub>CE</sub>	5	7	5	ŝ	7	ŝ	S	S	ŝ	ŝ	S	'n	2	8	ო	~	2	3	Ŋ	9	8	S	2	ŝ	ŝ	Ŋ	9
	LEB() max	1.0µ	1.0µ	1.0 μ	$1.0\mu$	1.0 μ	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	33	3 ш	3 m	0.1m	0.1m	0.1m	10 <i>µ</i>	I5μ	10 µ	1 μ	0.1 μ	1 µ	1 μ	1μ	1 μ
	VEB	4	4	4	-4-	4	4	4	4	4	4	4	4	<u>م</u>	ŝ	5	4	4	4	4	9	4	4	ę	4	4	4	4
	I <sup>(BO)</sup>	1.0 <i>µ</i>	1.0 μ	$1.0\mu$	1.0 μ	1.0 μ	0.1m	0.1m	0,1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	0.1m	10 μ	15 μ	15 <i>µ</i>	1 4	0.1 μ	1 μ	1 µ	1 μ	ц ц
	A CB	20	8	5 20	8	8	40	80	8	8	8	8	\$	<del>\$</del>	40	8	8	8	ଛ	8	ន	150	33	35	ŝ	15	15	ж Х
25°C	Ţ,	125	125	5 125	5 125	125	0 150	0 150	150	150	0 150	0 150	150	150	150	150	150	150	150	2 150	8	150	175	175	175	175	175	125
gs/Ta≕	Ŀ	1		0.75	0.75	600m	150	160	480	180	1100	1100	†40	170	480	170	130	440	180	125	100m	600m	500m	500m	200m	600m	200m	200m
Ratin	u I,	1	1	0.7	0.7		9	1	80	80	11	13	9	01	15	80	വ	1	11	1.5	20m	50m	300m	300m	300m	300m	300m	100m
cimum	R VEBO	2	ى 	<u>م</u> ر	ິ	ŝ	9	9	9	9	9	9	9	9	9	9	9	9	9	9	9	4	ഹ	4	ŝ	പ	م	2 2
Absolute Maximum Ratings/Ta=25°C	V <sub>CEO</sub> †V <sub>CER</sub>	25	25	20	80	25	83	100	120	140	140	160	8	8	99	100	80	ଛ	8	180	1	1150 (11kΩ)	I	8	١	1	I	8
Abso	V <sub>CB0</sub>	25	R	8	10	8	100	120	150	150	160	180	100	02	2	110	120	120	120	180	8	150	\$	40	\$	କ୍ଷ	ន	40
Structure		S,EPL	S,EPL	S,EPL	S,EPL	S,EPL	S,EPL	S,EME	S,EME	S,EME	S,EME	S,EME	S, PL	S,EPL	S,EPL	S,EPL	S,EPL	S,EPL	S,EPL	S,TDP	G, AL	S, ME	S,EPL	S,EPL	S,EPL	S,EPL	S,EPL	S,TDP
Sase Outline		I	I	2006	I	1	1	2016	I	I	2017	2017	2010	2017	2017	2017	2010A	2010A	2022	2013	1	i	I	ı	I	1	l	1
Replacement		2SB544	(MP)		2SB560 (MP)	2SB598 (NP)			2SB816	2S B816	2SB817	2SB817		2SB912	2SB883	2SB913		~	-		2SC536 (SPNP)	25 CITE						2SC536 (SP,NP)
Applications		Cassette Tape Recorder Power Amp,	Electronic Governor, Driver	LF Power Amp, Medium Speed Switching	Audio Driver, General-purpose Amp	Electronic Governor DC-DC Converter, 1W Sound Output	LF Power Amp, 25 to 35W Output	LF Power Amp	LF Power Amp, 60W Output	Various Drivers	Various Drivers	Various Drivers	High Current Switching	High Current Switching	High Current Switching	Color TV Ver., Sound Output	TV Sync Separation	TV Video Output, HF Amp	HF, LF Amp, Switching	Switching, Amp	General-purpose Amp, Switching	General-purpose Amp, Switching	General-purpose Amp, Switching	Small Signal, General-purpose Amp				
Discontinued Package		Larger FP	Larger	Larger	FP	FP																						RE3
Type Number		2SB544(P1)	2SB544(P2)	2SB559	2SB560	2SB598	2SB633P	2SB634	2SB696	2SB696K	2SB697	2SB697K	2SB823	2SB914	2SB915	2SB916	2SB920	2SB921	2SB922	2SB991	2SC60	2SC65Y	2SC423	2SC423(S)	2SC424	2SC425	2SC426	2SC536
	<u> </u>				<u>.</u>				. <u></u> ,																		35	

This Material Copyrighted By Its Respective Manufacturer